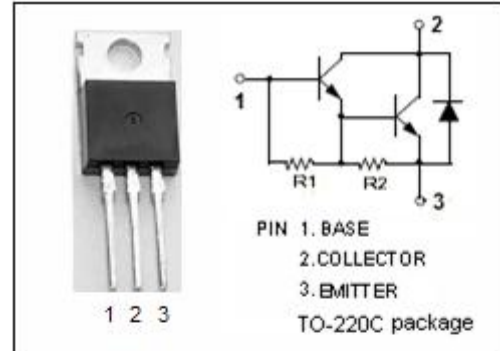


**isc Silicon NPN Darlington Power Transistor**
**BDT65/A/B/C**
**DESCRIPTION**

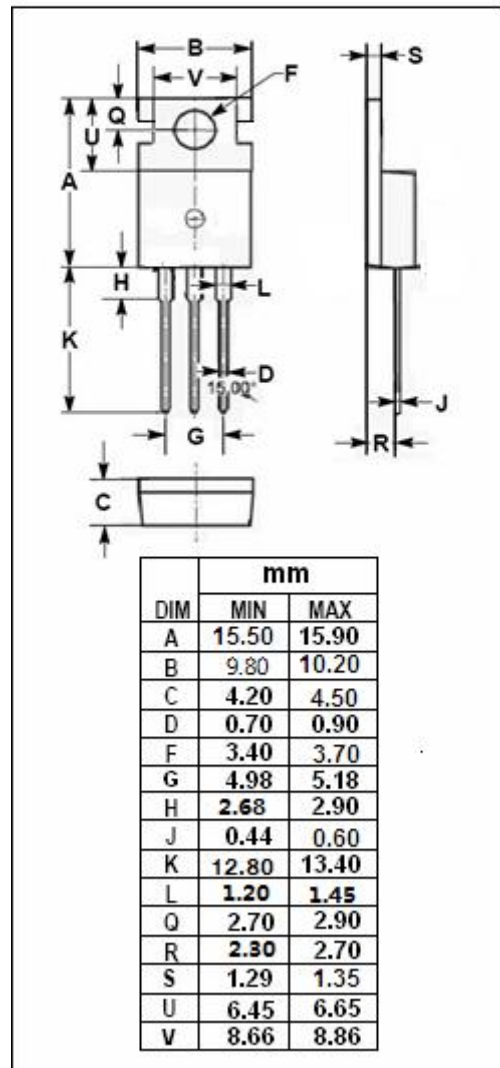
- Collector Current  $-I_C = 12A$
- High DC Current Gain  $-h_{FE} = 1000(\text{Min}) @ I_C = 5A$
- Complement to Type BDT64/A/B/C
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

**APPLICATIONS**

- Designed for audio output stages and general purpose amplifier applications


**ABSOLUTE MAXIMUM RATINGS ( $T_a = 25^\circ\text{C}$ )**

| SYMBOL    | PARAMETER  | VALUE   | UNIT             |   |
|-----------|--|---------|------------------|---|
| $V_{CER}$ | Collector-Emitter Voltage                              | BDT65   | 60               | V |
|           |  | BDT65A  | 80               |   |
|           |  | BDT65B  | 100              |   |
|           |  | BDT65C  | 120              |   |
| $V_{CEO}$ | Collector-Emitter Voltage                              | BDT65   | 60               | V |
|           |  | BDT65A  | 80               |   |
|           |  | BDT65B  | 100              |   |
|           |  | BDT65C  | 120              |   |
| $V_{EBO}$ | Emitter-Base Voltage                                   | 5       | V                |   |
| $I_C$     | Collector Current-Continuous                           | 12      | A                |   |
| $I_{CM}$  | Collector Current-Peak                                 | 20      | A                |   |
| $I_B$     | Base Current-Continuous                                | 0.5     | A                |   |
| $P_C$     | Collector Power Dissipation @ $T_C = 25^\circ\text{C}$ | 125     | W                |   |
| $T_J$     | Junction Temperature                                   | 150     | $^\circ\text{C}$ |   |
| $T_{stg}$ | Storage Temperature Range                              | -65~150 | $^\circ\text{C}$ |   |


**THERMAL CHARACTERISTICS**

| SYMBOL        | PARAMETER                            | MAX | UNIT                      |
|---------------|--------------------------------------|-----|---------------------------|
| $R_{th\ j-c}$ | Thermal Resistance, Junction to Case | 1   | $^\circ\text{C}/\text{W}$ |

**isc Silicon NPN Darlington Power Transistor**
**BDT65/A/B/C**
**ELECTRICAL CHARACTERISTICS**

 T<sub>C</sub>=25°C unless otherwise specified

| SYMBOL                 | PARAMETER                            | CONDITIONS  | MIN  | TYP. | MAX        | UNIT |
|------------------------|--------------------------------------|---|------|------|------------|------|
| V <sub>(BR)CEO</sub>   | Collector-Emitter Breakdown Voltage  | I <sub>C</sub> = 30mA ; I <sub>B</sub> =0   | 60   |      |            | V    |
|                        |                                      |   | 80   |      |            |      |
|                        |                                      |   | 100  |      |            |      |
|                        |                                      |   | 120  |      |            |      |
| V <sub>CE(sat)-1</sub> | Collector-Emitter Saturation Voltage | I <sub>C</sub> = 5A; I <sub>B</sub> = 20mA  |      |      | 2.0        | V    |
| V <sub>CE(sat)-2</sub> | Collector-Emitter Saturation Voltage | I <sub>C</sub> = 10A; I <sub>B</sub> = 100mA  |      |      | 3.0        | V    |
| V <sub>BE(on)</sub>    | Base-Emitter On Voltage              | I <sub>C</sub> = 5A ; V <sub>CE</sub> = 4V  |      |      | 2.5        | V    |
| V <sub>ECF-1</sub>     | C-E Diode Forward Voltage            | I <sub>F</sub> = 5A   |      |      | 2.0        | V    |
| V <sub>ECF-2</sub>     | C-E Diode Forward Voltage            | I <sub>F</sub> = 12A  |      | 2.0  |            | V    |
| I <sub>CEO</sub>       | Collector Cutoff Current             | V <sub>CE</sub> = 1/2V <sub>CEOmax</sub> ; I <sub>B</sub> = 0   |      |      | 0.2        | mA   |
| I <sub>CBO</sub>       | Collector Cutoff Current             | V <sub>CB</sub> = V <sub>CB0max</sub> ; I <sub>E</sub> = 0<br>V <sub>CB</sub> = 1/2V <sub>CB0max</sub> ; I <sub>E</sub> = 0; T <sub>C</sub> = 150°C |      |      | 0.4<br>2.0 | mA   |
| I <sub>EBO</sub>       | Emitter Cutoff Current               | V <sub>EB</sub> = 5V; I <sub>C</sub> =0   |      |      | 5          | mA   |
| h <sub>FE-1</sub>      | DC Current Gain                      | I <sub>C</sub> = 1A ; V <sub>CE</sub> = 4V  |      | 1500 |            |      |
| h <sub>FE-2</sub>      | DC Current Gain                      | I <sub>C</sub> = 5A ; V <sub>CE</sub> = 4V  | 1000 |      |            |      |
| h <sub>FE-3</sub>      | DC Current Gain                      | I <sub>C</sub> = 12A ; V <sub>CE</sub> = 4V   |      | 1000 |            |      |
| C <sub>OB</sub>        | Output Capacitance                   | I <sub>E</sub> = 0 ; V <sub>CB</sub> = 10V; f <sub>test</sub> =1MHz   |      | 200  |            | pF   |
| Switching times        |                                      |   |      |      |            |      |
| t <sub>on</sub>        | Turn-On Time                         | I <sub>C</sub> = 5A; I <sub>B1</sub> = -I <sub>B2</sub> = 20mA;<br>V <sub>CC</sub> = 30V  |      | 1    | 2.5        | μs   |
| t <sub>off</sub>       | Turn-Off Time                        |   |      | 6.0  | 10         | μs   |

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